

# International IR Rectifier

## PHASE CONTROL THYRISTORS

Bulletin I25164 rev. C 02/00

## Hockey Puk Version

350A

### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)

### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

case style TO-200AB (A-PUK)

### Major Ratings and Characteristics

Parameters	ST180C..C	Units
$I_{T(AV)}$	350	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	660	A
@ $T_{hs}$	25	°C
$I_{TSM}$	5000	A
@ 50Hz	5230	A
$I^2t$	125	KA <sup>2</sup> s
@ 60Hz	114	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 2000	V
$t_q$ typical	100	μs
$T_J$	- 40 to 125	°C

## ST180C..C Series

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### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J\max}$ mA
ST180C..C	04	400	500	30
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST180C..C	Units	Conditions
$I_{T(AV)}$	Max. average on-state current @ Heatsink temperature	A	180° conduction, half sine wave double side (single side) cooled
	55 (85)	°C	
$I_{T(RMS)}$	Max. RMS on-state current	660	@ 25°C heatsink temperature double side cooled
$I_{TSM}$	Max. peak, one-cycle non-repetitive surge current	5000	
		5230	
		4200	
		4400	
$I^2t$	Maximum $I^2t$ for fusing	125	Sinusoidal half wave, Initial $T_J = T_{J\max}$ .
		114	
		88	
		81	
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	1250	$KA^2/s$ $t = 0.1$ to 10ms, no voltage reapplied
$V_{T(TO)1}$	Low level value of threshold voltage	1.08	$V$ $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$V_{T(TO)2}$	High level value of threshold voltage	1.14	
$r_{t1}$	Low level value of on-state slope resistance	1.18	$m\Omega$ $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$r_{t2}$	High level value of on-state slope resistance	1.14	
$V_{TM}$	Max. on-state voltage	1.96	$V$ $I_{pk} = 750A$ , $T_J = T_{J\max}$ , $t_p = 10ms$ sine pulse
$I_H$	Maximum holding current	600	$mA$ $T_J = T_{J\max}$ , anode supply 12V resistive load
$I_L$	Max. (typical) latching current	1000 (300)	

### Switching

Parameter	ST180C..C	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/μs
t <sub>d</sub>	Typical delay time	1.0	μs
t <sub>q</sub>	Typical turn-off time	100	I <sub>TM</sub> = 300A, T <sub>J</sub> = T <sub>J</sub> max, di/dt = 20A/μs, V <sub>R</sub> = 50V dv/dt = 20V/μs, Gate 0V 100Ω, t <sub>p</sub> = 500μs

### Blocking

Parameter	ST180C..C	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/μs T <sub>J</sub> = T <sub>J</sub> max linear to 80% rated V <sub>DRM</sub>
I <sub>DRM</sub> I <sub>RRM</sub>	Max. peak reverse and off-state leakage current	30	mA T <sub>J</sub> = T <sub>J</sub> max, rated V <sub>DRM</sub> /V <sub>RRM</sub> applied

### Triggering

Parameter	ST180C..C	Units	Conditions
P <sub>GM</sub>	Maximum peak gate power	10	W T <sub>J</sub> = T <sub>J</sub> max, t <sub>p</sub> ≤ 5ms
P <sub>G(AV)</sub>	Maximum average gate power	2.0	W T <sub>J</sub> = T <sub>J</sub> max, f = 50Hz, d% = 50
I <sub>GM</sub>	Max. peak positive gate current	3.0	A T <sub>J</sub> = T <sub>J</sub> max, t <sub>p</sub> ≤ 5ms
+V <sub>GM</sub>	Maximum peak positive gate voltage	20	V
-V <sub>GM</sub>	Maximum peak negative gate voltage	5.0	V T <sub>J</sub> = T <sub>J</sub> max, t <sub>p</sub> ≤ 5ms
I <sub>GT</sub>	DC gate current required to trigger	TYP. 180 90 40	mA T <sub>J</sub> = - 40°C T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
V <sub>GT</sub>	DC gate voltage required to trigger	2.9 1.8 1.2	V T <sub>J</sub> = - 40°C T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C
I <sub>GD</sub>	DC gate current not to trigger	10	mA T <sub>J</sub> = T <sub>J</sub> max Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V <sub>DRM</sub> anode-to-cathode applied
V <sub>GD</sub>	DC gate voltage not to trigger	0.25	V T <sub>J</sub> = T <sub>J</sub> max

## ST180C..C Series

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### Thermal and Mechanical Specification

Parameter	ST180C..C	Units	Conditions
$T_J$	Max. operating temperature range	$^{\circ}\text{C}$	DC operation single side cooled DC operation double side cooled
$T_{\text{stg}}$	Max. storage temperature range		
$R_{\text{thJ-hs}}$	Max. thermal resistance, junction to heatsink	K/W	DC operation single side cooled DC operation double side cooled
$R_{\text{thC-hs}}$	Max. thermal resistance, case to heatsink		
F	Mounting force, $\pm 10\%$	4900 (500)	N (Kg)
wt	Approximate weight	50	g
Case style	TO - 200AB (A-PUK)	See Outline Table	

### $\Delta R_{\text{thJ-hs}}$ Conduction

(The following table shows the increment of thermal resistance  $R_{\text{thJ-hs}}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.015	0.015	0.011	0.011	K/W	$T_J = T_{\text{J max}}$
120°	0.018	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

### Ordering Information Table

Device Code		ST 18 0 C 20 C 1							
		1	2	3	4	5	6	7	8
<b>1</b>	- Thyristor								
<b>2</b>	- Essential part number								
<b>3</b>	- 0 = Converter grade								
<b>4</b>	- C = Ceramic Puk								
<b>5</b>	- Voltage code: Code x 100 = $V_{\text{RRM}}$ (See Voltage Rating Table)								
<b>6</b>	- C = Puk Case TO-200AB (A-PUK)								
<b>7</b>	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)								
<b>8</b>	- Critical dv/dt: None = 500V/ $\mu\text{sec}$ (Standard value) L = 1000V/ $\mu\text{sec}$ (Special selection)								

Outline Table

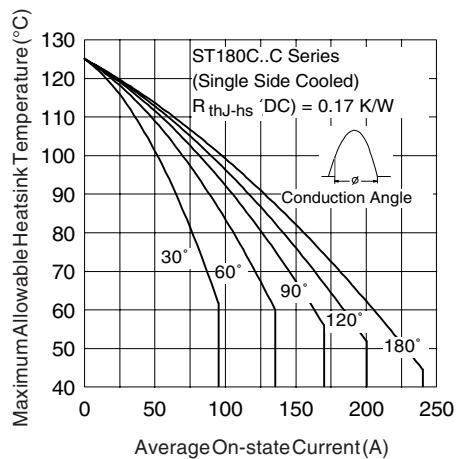
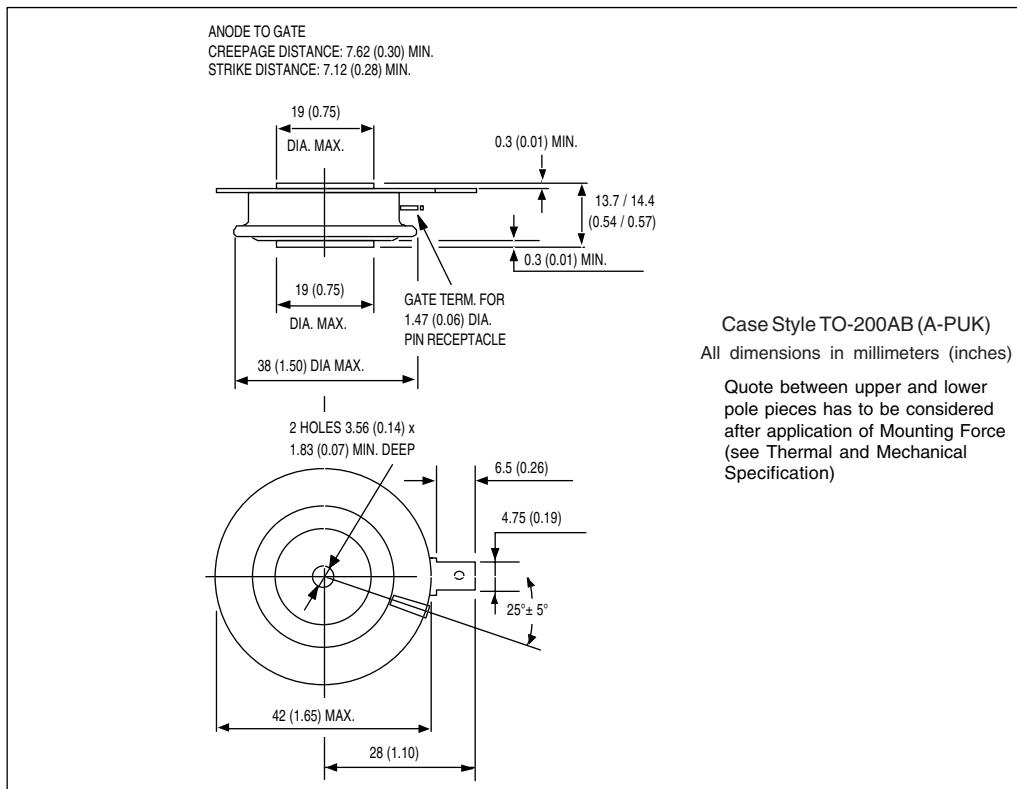


Fig. 1 - Current Ratings Characteristics

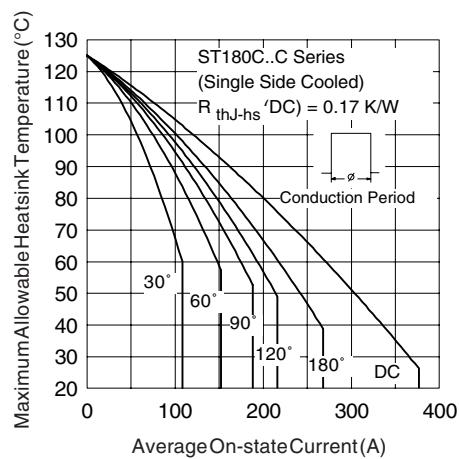


Fig. 2 - Current Ratings Characteristics

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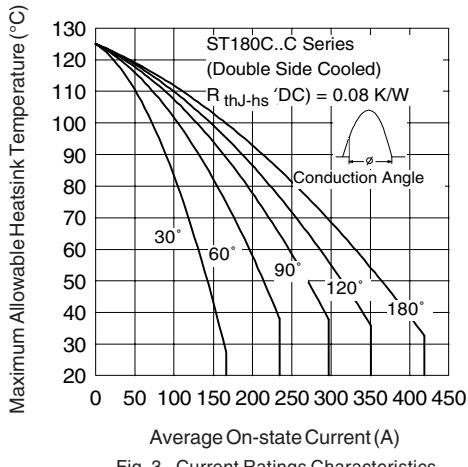


Fig. 3 - Current Ratings Characteristics

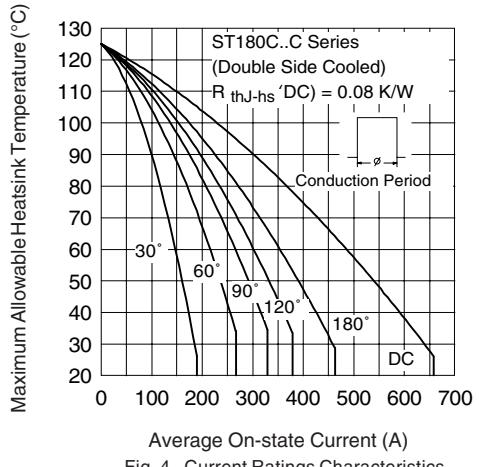


Fig. 4 - Current Ratings Characteristics

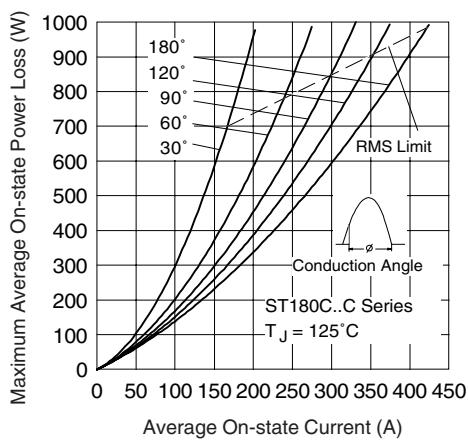


Fig. 5 - On-state Power Loss Characteristics

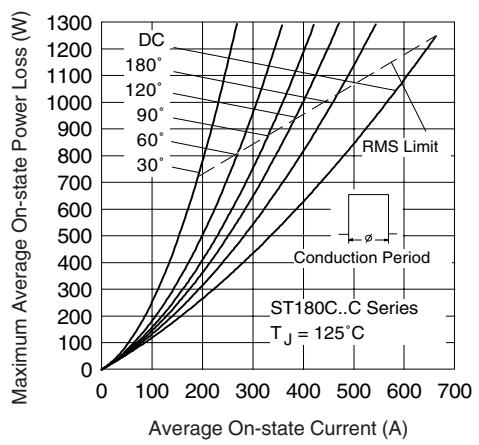


Fig. 6 - On-state Power Loss Characteristics

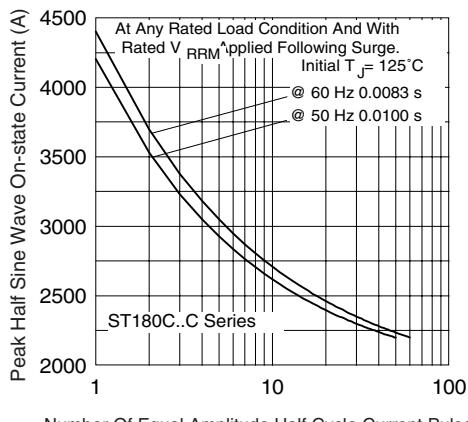


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

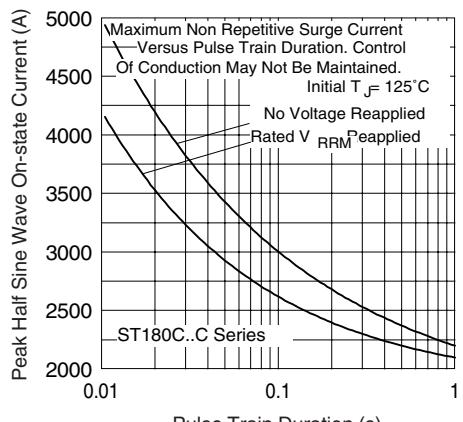


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

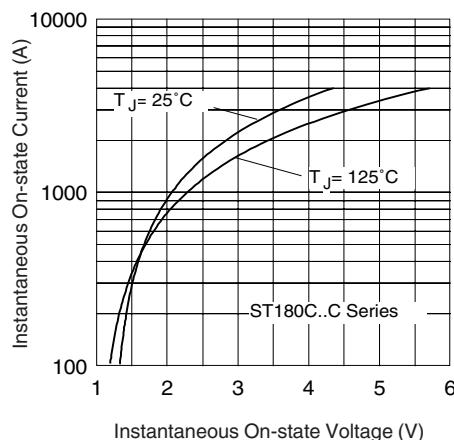


Fig. 9 - On-state Voltage Drop Characteristics

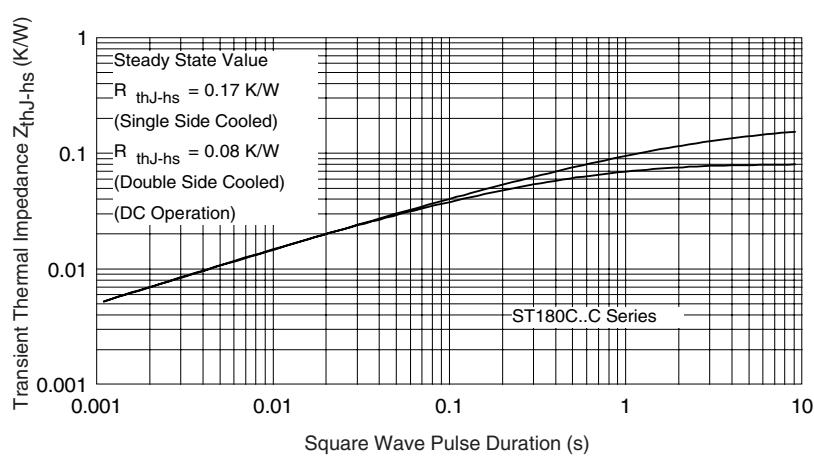


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

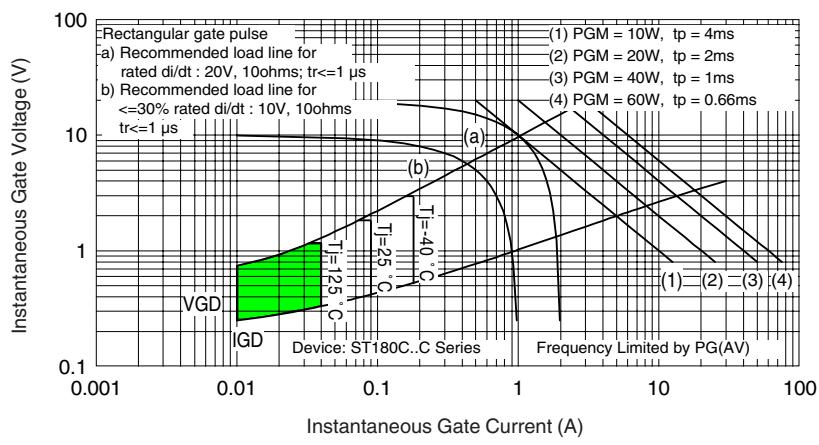


Fig. 11 - Gate Characteristics